



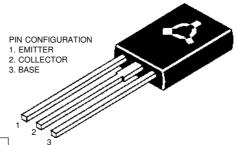


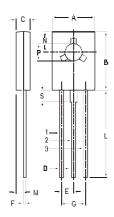
## TO-126 (SOT-32) Plastic Package

BD136, BD138, BD140

## BD136, 138, 140 PNP PLASTIC POWER TRANSISTORS

Complementary BD135, 137, 139 Medium Power Linear and Switching Applications





DIM	MIN.	MAX.		
A	7.4	7.8		
В	10.5	10.8		
С	2.4	2.7		
D	0.7	0.9		
Е	2.25 TYP.			
F	0.49	0.75		
G	4.5 TYP.			
L	15.7 TYP.			
М	1.27 TYP.			
N	3.75 TY <b>P</b> .			
Р	3.0	3.2		
Ş	2.5	TYP.		

ABSOLUTE MAXIMUM RATINGS

Emitter-base voltage (open collector)

TIBOOLGIL THIRMITON TETTINGS						
			136	138	140	
Collector-base voltage (open emitter)	$V_{CBO}$	max.	45	60	100	V
Collector-emitter voltage (open base)	$V_{CEO}$	max.	45	60	80	V
Collector current	$I_C$	max.		1.5		A
Total power dissipation up to $T_C = 25^{\circ}C$	$P_{tot}$	max.		12.5		W
Junction temperature	$T_i$	max.		150		$^{\circ}C$
Collector-emitter saturation voltage	,					
$I_C = 0.5 A$ ; $I_B = 0.05 A$	$V_{CEsat}$	max.		0.5		V
D.C. current gain						
$I_C = 0.15 A; V_{CE} = 2 V$	$h_{FE}$	min.		40		
-		max.		250		
<b>RATINGS</b> (at $T_A$ =25°C unless otherwise specified)						
Limiting values			136	138	140	
Collector-base voltage (open emitter)	$V_{CBO}$	max.	45	60	100	V
Collector-emitter voltage (open base)	$V_{CEO}$	max.	45	60	80	V
	CLO					

 $V_{EBO}$ 

max.

5.0

Collector current Base current Total power dissipation up to $T_A = 25^{\circ}\text{C}$ Derate above $25^{\circ}\text{C}$ Total power dissipation up to $T_C = 25^{\circ}\text{C}$ Derate above $25^{\circ}\text{C}$ Junction temperature Storage temperature THERMAL RESISTANCE	$I_{C}$ $I_{B}$ $P_{tot}$ $P_{tot}$ $T_{j}$ $T_{stg}$	max. max. max. max max. max	1.5 0.5 1.25 10 12.5 100 150 -65 to +150		150	$\begin{array}{c} A \\ A \\ W \\ mW/ \mathbb{C} \\ W \\ mW/ \mathbb{C} \\ \mathbb{C} \\ \end{array}$
From junction to case	$R_{th\ jc}$			10		°C/W
From junction to ambient	R <sub>th ja</sub>			100		°C/W
CHARACTERISTICS $T_{amb} = 25^{\circ}\text{C}$ unless otherwise specified Collector cutoff current			136	138	140	
$I_E = 0; V_{CB} = 30 \text{ V}$	$I_{CBO}$	max.		0.1		$\mu A$
$I_E = 0$ ; $V_{CB} = 30 \text{ V}$ ; $T_C = 125^{\circ}\text{C}$	$I_{CBO}$	max.		10		μA
Emitter cut-off current	CDC					'
$I_C = 0; V_{EB} = 5 V$	$I_{EBO}$	max.		10		$\mu A$
Breakdown voltages						
$I_C = 0.03 \ A; I_B = 0$	$V_{CEO(sus)}^*$	min.	45	60	80	V
$I_C = 1 \ mA; I_E = 0$	$V_{CBO}$	min.	45	60	100	V
$I_E = 1 mA; I_C = 0$	$V_{EBO}$	min.		5.0		V
Saturation voltage						
$I_C = 0.5 A; I_B = 0.05 A$	$V_{CEsat}^*$	max.		0.5		V
Base-emitter on voltage						
$I_C = 0.5A; V_{CE} = 2V$	$V_{BE(on)}^*$	max.		1.0		V
D.C. current gain	1 4			25		
$I_C = 0.005 A; V_{CE} = 2 V^*$	$h_{FE}^*$	min.		25		
$I_C = 0.15 A; V_{CE} = 2 V^{**}$	$h_{FE}^*$	min.		40		
IC = 0.13 M, $VCE = 2 V$	n <sub>FE</sub>	max.		250		
		тих.		250		
$I_C = 0.5 A; V_{CE} = 2 V^*$	$h_{FE}^*$	min.		25		
ac and any a CL	T L					
** hFE classification:	-6	min.	40			
,		max.	100			
	-10	min.	63			
	-10	max.	160			
	-16	min.	100			
		max.	250			
	-25	min.	160			
		max.	400			

<sup>\*</sup> Pulse test: pulse width  $\leq 300~\mu s, duty~cycle \leq 2\%.$ 

## **Notes**

## **Disclaimer**

The product information and the selection guides facilitate selection of the CDIL's Discrete Semiconductor Device(s) best suited for application in your product(s) as per your requirement. It is recommended that you completely review our Data Sheet(s) so as to confirm that the Device(s) meet functionality parameters for your application. The information furnished on the CDIL Web Site/CD is believed to be accurate and reliable. CDIL however, does not assume responsibility for inaccuracies or incomplete information. Furthermore, CDIL does not assume liability whatsoever, arising out of the application or use of any CDIL product; neither does it convey any license under its patent rights nor rights of others. These products are not designed for use in life saving/support appliances or systems. CDIL customers selling these products (either as individual Discrete Semiconductor Devices or incorporated in their end products), in any life saving/support appliances or systems or applications do so at their own risk and CDIL will not be responsible for any damages resulting from such sale(s).

CDIL strives for continuous improvement and reserves the right to change the specifications of its products without prior notice.



CDIL is a registered Trademark of
Continental Device India Limited
C-120 Naraina Industrial Area, New Delhi 110 028, India.
Telephone + 91-11-579 6150 Fax + 91-11-579 9569, 579 5290
e-mail sales@cdil.com www.cdil.com